

# isc N-Channel MOSFET Transistor

### **TK11P65W**

<ul> <li>FEATURES</li> <li>Low drain-source on-resistance: RDs(on) ≤0.44Ω.</li> <li>Enhancement mode: Vth =2.5 to 3.5V (VDs = 10 V, ID=0.45mA)</li> <li>100% avalanche tested</li> <li>Minimum Lot-to-Lot variations for robust device performance and reliable operation</li> <li>DESCRITION</li> </ul>				
	ing Voltage Regulators			
• ABSOI	LUTE MAXIMUM RATINGS(Ta=25° PARAMETER	C) VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	650	v	
$V_{GS}$	Gate-Source Voltage	±30	v	
ID	Drain Current-Continuous	11.1	A	
I <sub>DM</sub>	Drain Current-Single Pulsed	44.4	A	
PD	Total Dissipation @Tc=25℃	100	w	
Tj	Max. Operating Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	°C	
• THERN	MAL CHARACTERISTICS	1		
SYMBOL	PARAMETER	МАХ	UNIT	

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#### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =10mA	650			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =10V; I <sub>D</sub> =0.45mA	2.5		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =5.5A			0.44	Ω
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V			±1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0V			10	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =11.1A, V <sub>GS</sub> = 0 V			1.7	V



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